SN54ALVTH16244, SN74ALVTH16244 2.5-V/3.3-V 16-BIT BUFFERS/DRIVERS WITH 3-STATE OUTPUTS

SN54ALVTH16244 . . . WD PACKAGE

SN74ALVTH16244 . . . DGG, DGV, OR DL PACKAGE

(TOP VIEW)

10F L

1Y1 🛮

1Y2 🛛 3

GND 🛮 4

1Y3 🛮 5

1Y4 🛮 6

V_{CC} \square 7

2Y1 🛮 8

2Y2 🛮 9

GND 1 10

2Y3 🛮 11

2Y4 🛮 12

3Y1 [] 13

3Y2 🛮 14

GND [

3Y3 🛚

3Y4

v_{cc}[18

4Y1 19

4Y2 🛮 20

GND 1 21

4Y3 22

4Y4 🛮 23

40E 24

15

17

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48 20E

47 🛮 1A1

46 1 1A2

45 GND

44 🛮 1A3

43 🛮 1A4

42 V_{CC}

41 2A1

40 2A2

39 | GND

38 2A3

37 2A4

36 | 3A1

35 3A2

34 GND

33 | 3A3

32 3A4 31 V_{CC}

30 4A1

29 4A2

28 GND

27 4A3

26 🛮 4A4

25 3OE

- **Members of the Texas Instruments** Widebus™ Family
- State-of-the-Art Advanced BiCMOS Technology (ABT) Design for 3.3-V **Operation and Low Static-Power** Dissipation
- 5-V I/O Compatible
- High Drive Capability (-32 mA/64 mA)
- Support Mixed-Mode Signal Operation (5-V Input and Output Voltages With 3.3-V V_{CC})
- **Support Unregulated Battery Operation** Down to 2.3 V
- Typical V_{OI P} (Output Ground Bounce) $< 0.8 \text{ V at V}_{CC} = 3.3 \text{ V}, T_A = 25^{\circ}\text{C}$
- **Auto3-State Eliminates Bus Current Loading When Voltage at the Output** Exceeds V_{CC}
- Ioff and Power-Up 3-State Support Hot Insertion
- Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors
- Latch-Up Performance Exceeds 250 mA Per **JESD 17**
- **ESD Protection Exceeds 2000 V Per** MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)

The 'ALVTH16244 devices are 16-bit buffers/line drivers designed for 2.5-V or 3.3-V V_{CC} operation, but with the capability to provide a TTL interface to a 5-V system environment. These devices can be used as four 4-bit buffers, two 8-bit buffers, or one 16-bit buffer.

Active bus-hold circuitry is provided to hold unused or floating data inputs at a valid logic level.

Package Options Include Plastic 300-mil Shrink Small-Outline (DL), Thin Shrink Small-Outline (DGG), Thin Very Small-Outline (DGV) Packages, and 380-mil Fine-Pitch Ceramic Flat (WD) Package NOTE: For tape and reel order entry: The DGGR package is abbreviated to GR, and the DGVR package is abbreviated to VR. description



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description (continued)

When V_{CC} is between 0 and 1.2 V, the device is in the high-impedance state during power up or power down. However, to ensure the high-impedance state above 1.2 V, the output-enable (\overline{OE}) input should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

These devices are fully specified for hot-insertion applications using $I_{\rm off}$ and power-up 3-state. The $I_{\rm off}$ circuitry disables the outputs, preventing damaging current backflow through the devices when they are powered down. The power-up 3-state circuitry places the outputs in the high-impedance state during power up and power down, which prevents driver conflict.

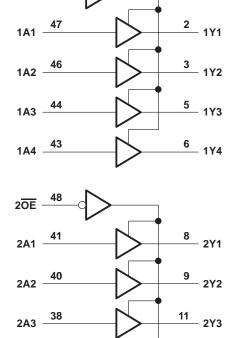
The SN54ALVTH16244 is characterized for operation over the full military temperature range of –55°C to 125°C. The SN74ALVTH16244 is characterized for operation from –40°C to 85°C.

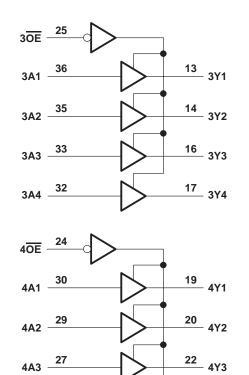
FUNCTION TABLE (each buffer)

INP	JTS	OUTPUT
ŌĒ	Α	Υ
L	Н	Н
L	L	L
Н	Χ	Z

logic diagram (positive logic)

2A4 —





23

4Y4



12 _

2Y4

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC}	0.5 V to 4.6 V
Input voltage range, V _I (see Note 1)	0.5 V to 7 V
Voltage range applied to any output in the high-impedance	
or power-off state, V _O (see Note 1)	–0.5 V to 7 V
Voltage range applied to any output in the high state, VO (see Note 1) .	\dots -0.5 V to V _{CC} to 7V
Output current in the low state, IO: SN54ALVTH16244	
SN74ALVTH16244	128 mA
Output current in the high state, IO: SN54ALVTH16244	
SN74ALVTH16244	–64 mA
Input clamp current, I _{IK} (V _I < 0)	
Output clamp current, I _{OK} (V _O < 0)	
Package thermal impedance, θ _{JA} (see Note 2): DGG package	89°C/W
DGV package	93°C/W
	94°C/W
Storage temperature range, T _{stg}	

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

2. The package thermal impedance is calculated in accordance with JESD 51.

recommended operating conditions, V_{CC} = 2.5 V \pm 0.2 V (see Note 3)

			SN54ALV	ГН16244	SN74ALVT	H16244	UNIT
			MIN	MAX	MIN	MAX	UNIT
V _{CC}	Supply voltage		2.3	2.7	2.3	2.7	V
VIH	High-level input voltage	1.7	2	1.7		V	
V _{IL}	Low-level input voltage			0.7		0.7	V
VI	Input voltage	0	5.5	0	5.5	V	
IOH	High-level output current		1	-6		-8	mA
lo	Low-level output current		2	6		8	mA
lor	Low-level output current; current duty cycle ≤ 50%; f ≥	1 kHz	70,	18		24	IIIA
Δt/Δν	Input transition rise or fall rate	Outputs enabled	Q	10		10	ns/V
Δt/ΔV _{CC}	Power-up ramp rate		200		200		μs/V
T _A	Operating free-air temperature		-55	125	-40	85	°C

NOTE 3: All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

SN54ALVTH16244, SN74ALVTH16244 2.5-V/3.3-V 16-BIT BUFFERS/DRIVERS WITH 3-STATE OUTPUTS

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recommended operating conditions, $V_{\mbox{\footnotesize{CC}}}$ = 3.3 V \pm 0.3 V (see Note 3)

			SN54ALV	ГН16244	SN74ALVT	H16244	UNIT
			MIN	MAX	MIN	MAX	UNIT
V _{CC}	Supply voltage	3	3.6	3	3.6	V	
VIH	High-level input voltage		2	2	2		V
V _{IL}	Low-level input voltage		8.0		0.8	V	
VI	Input voltage	0	5.5	0	5.5	V	
Іон	High-level output current		7	-24		-32	mA
lou	Low-level output current		20	24		32	mA
lor	Low-level output current; current duty cycle ≤ 50%; f ≥	1 kHz	70,	48		64	IIIA
Δt/Δν	Input transition rise or fall rate	Outputs enabled	Q	10		10	ns/V
Δt/ΔVCC	Power-up ramp rate	200		200		μs/V	
TA	Operating free-air temperature		-55	125	-40	85	°C

NOTE 3: All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

electrical characteristics over recommended operating free-air temperature range, V_{CC} = 2.5 V \pm 0.2 V (unless otherwise noted)

DA	DAMETED	TEST OF	NUNTIONS	SN54	ALVTH1	6244	SN74	ALVTH1	6244	UNIT
PAI	RAMETER	lESI CC	ONDITIONS	MIN	TYP [†]	MAX	MIN	TYP [†]	MAX	UNII
٧ıK		$V_{CC} = 2.3 \text{ V},$	I _I = -18 mA			-1.2			-1.2	V
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V},$	I _{OH} = -100 μA	V _{CC} -0	.2		V _{CC} -0	.2		
Vон		V _{CC} = 2.3 V	$I_{OH} = -6 \text{ mA}$	1.8						V
		VCC = 2.3 V	$I_{OH} = -8 \text{ mA}$				1.8			
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V},$	$I_{OL} = 100 \mu A$			0.2			0.2	
			$I_{OL} = 6 \text{ mA}$			0.4				
VOL		V _{CC} = 2.3 V	$I_{OL} = 8 \text{ mA}$						0.4	V
		V(C) = 2.3 V	$I_{OL} = 18 \text{ mA}$			0.5				
			$I_{OL} = 24 \text{ mA}$						0.5	
	Control inputs	$V_{CC} = 2.7 \text{ V},$	$V_I = V_{CC}$ or GND			±1			±1	
1.	Control inputs	$V_{CC} = 0 \text{ or } 2.7 \text{ V},$	V _I = 5.5 V			\$ 10			10	μΑ
łį	Data inputs	V _{CC} = 2.7 V	AI = ACC		1				1	μΑ
	Data inputs	VCC = 2.7 V	V _I = 0		72	- 5			– 5	
l _{off}		$V_{CC} = 0$,	V_I or $V_O = 0$ to 4.5 V		1				±100	μΑ
		V _{CC} = 2.3 V	V _I = 0.7 V		115			115		
I _{I(hold)}	Data inputs	VCC = 2.3 V	V _I = 1.7 V	000	-10			-10		μΑ
, ,		$V_{CC} = 2.7 V^{\ddagger}$,	$V_{I} = 0 \text{ to } 2.7 \text{ V}$	Q		±300			±300	
I _{EX} §		$V_{CC} = 2.3 \text{ V},$	$V_0 = 5.5 V$			125			125	μΑ
IOZ(PU	_{/PD)} ¶	$V_{CC} \le 1.2 \text{ V}, V_{O} = \underline{0.5} \text{ V}$ $V_{I} = \text{GND or } V_{CC}, \overline{\text{OE}} =$	to V _{CC} , don't care			±100			±100	μΑ
lozh		V _{CC} = 2.7 V	$V_O = 2.3 \text{ V},$ $V_I = 0.7 \text{ V or } 1.7 \text{ V}$			5			5	μΑ
lozL		V _{CC} = 2.7 V	V _O = 0.5 V, V _I = 0.7 V or 1.7 V			- 5			- 5	μΑ
		V _{CC} = 2.7 V,	Outputs high		0.04	0.1		0.04	0.1	
ICC	$I_{O} = 0$		Outputs low		2.3	4.5		2.3	4.5	mA
	VI = VCC	$V_I = V_{CC}$ or GND	Outputs disabled		0.04	0.1		0.04	0.1	
Ci		V _{CC} = 2.5 V,	V _I = 2.5 V or 0		3			3		рF
Со		V _{CC} = 2.5 V,	V _O = 2.5 V or 0		6			6		pF
			-							

 $[\]uparrow$ All typical values are at V_{CC} = 2.5 V, T_A = 25°C.



[‡] This is the bus-hold maximum dynamic current. It is the minimum overdrive current required to switch the input from one state to another.

 $[\]S$ Current into an output in the high state when $V_O > V_{CC}$

[¶] High-impedance state during power up/power down

SN54ALVTH16244, SN74ALVTH16244 2.5-V/3.3-V 16-BIT BUFFERS/DRIVERS WITH 3-STATE OUTPUTS

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electrical characteristics over recommended operating free-air temperature range, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted)

DAI	PARAMETER	TEST	CONDITIONS	SN54	ALVTH1	6244	SN74	ALVTH1	6244	LINUT
PAR	RAMETER	l lesi c	CONDITIONS	MIN	TYP [†]	MAX	MIN	TYP [†]	MAX	UNIT
VIK		V _{CC} = 3 V,	I _I = -18 mA			-1.2			-1.2	V
		$V_{CC} = 3 \text{ V to } 3.6 \text{ V},$	I _{OH} = -100 μA	V _{CC} -0	.2		V _{CC} -0.2			
Vон		V 2.V	I _{OH} = -24 mA	2						V
		VCC = 3 V	$I_{OH} = -32 \text{ mA}$				2			
		$V_{CC} = 3 \text{ V to } 3.6 \text{ V},$	I _{OL} = 100 μA			0.2			0.2	
			I _{OL} = 16 mA						0.4	
/.			$I_{OL} = 24 \text{ mA}$			0.5				V
VOL		V _{CC} = 3 V	$I_{OL} = 32 \text{ mA}$						0.5	V
			I _{OL} = 48 mA			0.55				
			$I_{OL} = 64 \text{ mA}$						0.55	
	Control inputs	$V_{CC} = 3.6 \text{ V},$	$V_I = V_{CC}$ or GND			±1			±1	
	Control inputs	$V_{CC} = 0 \text{ or } 3.6 \text{ V},$	V _I = 5.5 V			10			10	
lį			V _I = 5.5 V	T		20			20	μΑ
	Data inputs	V _{CC} = 3.6 V	VI = VCC	T	1				1	
			V _I = 0		E C	- 5			- 5	
l _{off}		$V_{CC} = 0$,	V_I or $V_O = 0$ to 4.5 V		DA				±100	μΑ
1		V 2.V	V _I = 0.8 V	75	Ç		75			
II(hold)	Data inputs	VCC = 3 V	V _I = 2 V	-75	20		-75			μΑ
. ,		$V_{CC} = 3.6 V^{\ddagger}$,	$V_{I} = 0 \text{ to } 3.6 \text{ V}$	B		±500			±500	
I _{EX} §		V _{CC} = 3 V,	V _O = 5.5 V			125			125	μΑ
IOZ(PU/	_{/PD)} ¶	$V_{CC} \le 1.2 \text{ V}, V_{O} = 0.5 \text{ V}_{I} = \text{GND or } V_{CC}, \overline{\text{OE}} = 0.5 \text{ OE}$	V to V _{CC} , = don't care			±100			±100	μΑ
lozh		V _{CC} = 3.6 V	V _O = 3 V, V _I = 0.8 V or 2 V			5			5	μΑ
lozL		V _{CC} = 3.6 V	V _O = 0.5 V, V _I = 0.8 V or 2 V			- 5			- 5	μΑ
		V _{CC} = 3.6 V,	Outputs high		0.07	0.1		0.07	0.1	
Icc	CC $I_{C}=0$,		Outputs low		3.2	5		3.2	5	mA
		V _I = V _{CC} or GND	Outputs disabled		0.07	0.1		0.07	0.1	
Δl _{CC} #		$V_{CC} = 3 \text{ V to } 3.6 \text{ V, On}$ Other inputs at V_{CC} or				0.4			0.4	mA
Ci		V _{CC} = 3.3 V,	V _I = 3.3 V or 0		3			3		pF
Со		V _{CC} = 3.3 V,	V _O = 3.3 V or 0		6			6		pF

[†] All typical values are at $V_{CC} = 3.3 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

[‡] This is the bus-hold maximum dynamic current. It is the minimum overdrive current required to switch the input from one state to another.

 $[\]S$ Current into an output in the high state when $V_O > V_{CC}$

[¶] High-impedance state during power up/power down

[#]This is the increase in supply current for each input that is at the specified TTL voltage level rather than V_{CC} or GND.

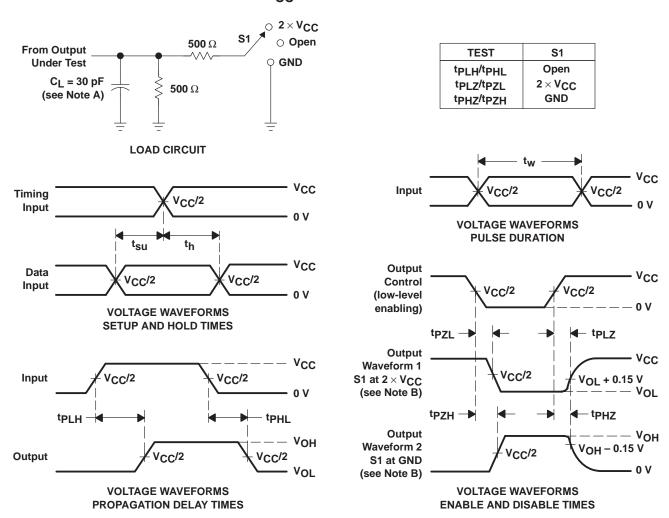
switching characteristics over recommended operating free-air temperature range, C_L = 30 pF, V_{CC} = 2.5 V \pm 0.2 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	SN54ALV	ГН16244	SN74ALVT	UNIT	
PARAMETER	(INPUT) (OUTPUT)		MIN	MAX	MIN	MAX	UNIT
t _{PLH}	۸	V	1	3.1	1	3	ns
^t PHL	А	ı	1	3.6	1	3.5	115
^t PZH	-	V	1.1	6	1.1	5.9	ns
^t PZL	OE	ı	1.150	4.8	1.1	4.7	115
^t PHZ	ŌĒ	V	1.5	4.5	1.5	4.4	ns
t _{PLZ}	OE .	ı.	Q 1	3.5	1	3.4	110

switching characteristics over recommended operating free-air temperature range, C_L = 50 pF, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted) (see Figure 2)

PARAMETER	FROM	ТО	SN54ALVT	H16244	SN74ALVT	UNIT	
PARAMETER	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	UNII
t _{PLH}	Α	V	1	2.6	1	2.4	ns
^t PHL	A	ı	1	2.6	1	2.5	115
^t PZH	-	V	1,0	3.9	1	3.8	ns
t _{PZL}	OE	ı	5	3	1	2.9	115
^t PHZ	ŌĒ	Y	1.5	4.3	1.5	4.2	ns
^t PLZ	OE .	ı	1.5	3.7	1.5	3.6	113

PARAMETER MEASUREMENT INFORMATION $V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$



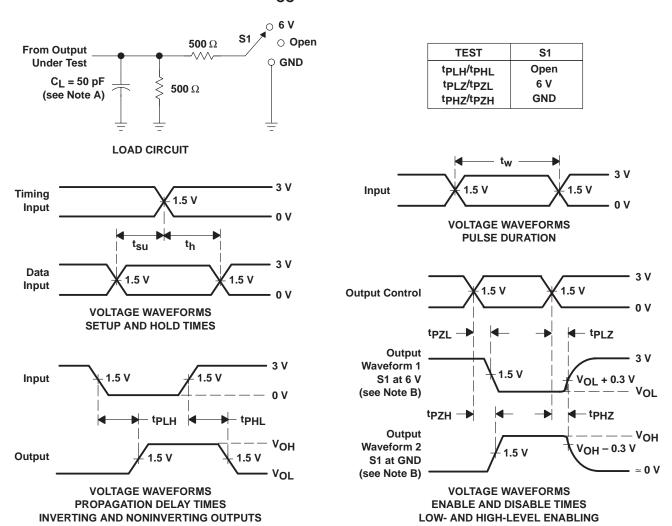
NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, $t_f \leq 2$ ns. $t_f \leq 2$ ns.
- D. The outputs are measured one at a time with one transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms



PARAMETER MEASUREMENT INFORMATION $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_Q = 50 \ \Omega$, $t_\Gamma \leq$ 2.5 ns, $t_f \leq$ 2.5 ns.
- D. The outputs are measured one at a time with one transition per measurement.

Figure 2. Load Circuit and Voltage Waveforms





10-Dec-2020

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
							(6)				
74ALVTH16244DLRG4	ACTIVE	SSOP	DL	48	1000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVTH16244	Samples
74ALVTH16244GRG4	ACTIVE	TSSOP	DGG	48	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVTH16244	Samples
74ALVTH16244VRE4	ACTIVE	TVSOP	DGV	48	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	VT244	Samples
SN74ALVTH16244DL	ACTIVE	SSOP	DL	48	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVTH16244	Samples
SN74ALVTH16244DLR	ACTIVE	SSOP	DL	48	1000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVTH16244	Samples
SN74ALVTH16244GR	ACTIVE	TSSOP	DGG	48	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVTH16244	Samples
SN74ALVTH16244VR	ACTIVE	TVSOP	DGV	48	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	VT244	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.



PACKAGE OPTION ADDENDUM

10-Dec-2020

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74ALVTH16244DLR	SSOP	DL	48	1000	330.0	32.4	11.35	16.2	3.1	16.0	32.0	Q1
SN74ALVTH16244GR	TSSOP	DGG	48	2000	330.0	24.4	8.6	13.0	1.8	12.0	24.0	Q1
SN74ALVTH16244VR	TVSOP	DGV	48	2000	330.0	16.4	7.1	10.2	1.6	12.0	16.0	Q1

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74ALVTH16244DLR	SSOP	DL	48	1000	367.0	367.0	55.0
SN74ALVTH16244GR	TSSOP	DGG	48	2000	367.0	367.0	45.0
SN74ALVTH16244VR	TVSOP	DGV	48	2000	356.0	356.0	35.0

PACKAGE MATERIALS INFORMATION

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TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
SN74ALVTH16244DL	DL	SSOP	48	25	473.7	14.24	5110	7.87

DGV (R-PDSO-G**)

24 PINS SHOWN

PLASTIC SMALL-OUTLINE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.

D. Falls within JEDEC: 24/48 Pins – MO-153 14/16/20/56 Pins – MO-194

DL (R-PDSO-G48)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

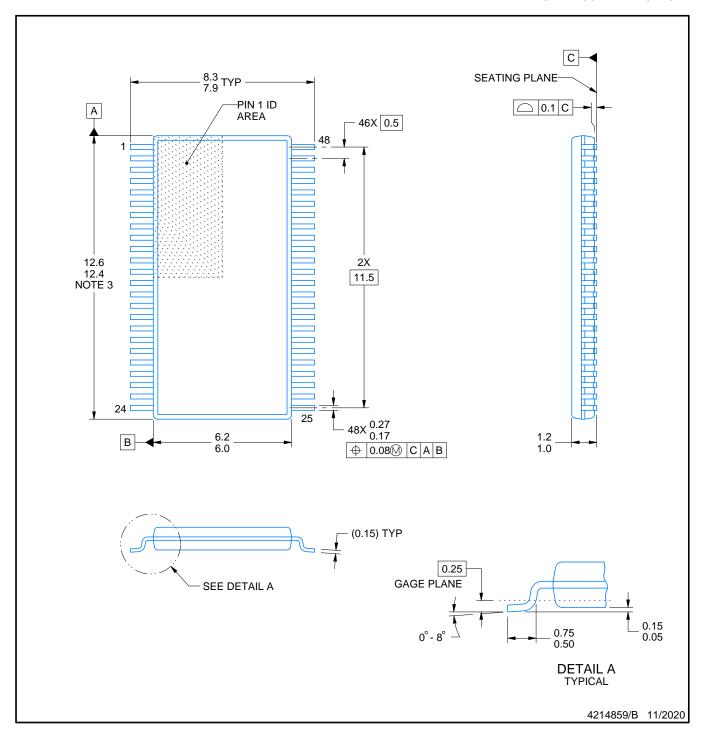
- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MO-118

PowerPAD is a trademark of Texas Instruments.





SMALL OUTLINE PACKAGE



NOTES:

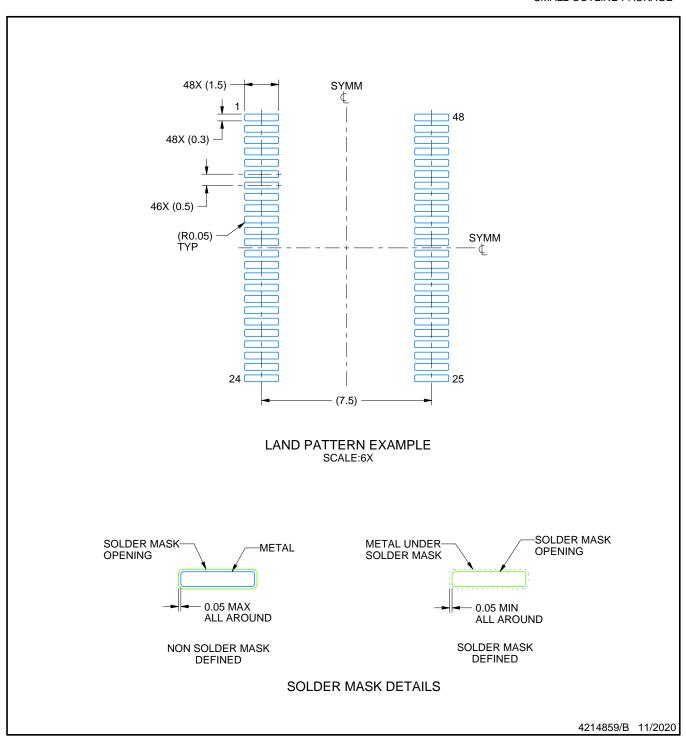
- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
 4. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE

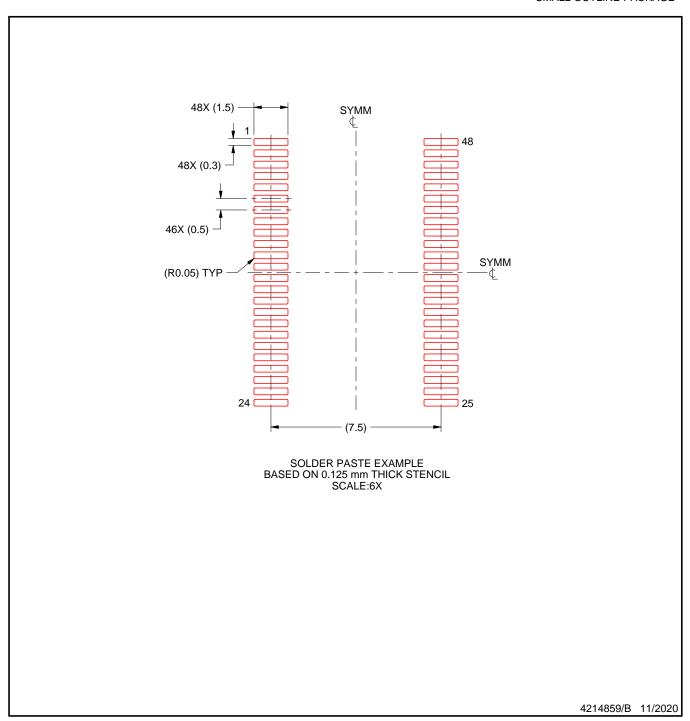


NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.



DGG (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

48 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

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